







DRV8885

SLVSD39D-OCTOBER 2015-REVISED MARCH 2020

DRV8885 1.5-A Stepper Motor Driver With Integrated Current Sense

1 Features

Texas

INSTRUMENTS

- PWM microstepping stepper motor driver
 - Up to 1/16 microstepping
 - Non-circular and standard ½ step modes
- Integrated current sense functionality
 - No sense resistors required
 - ±6.25% Full-scale current accuracy
- · Slow and mixed decay options
- 8.0- to 37-V Operating supply voltage range
- Low R_{DS(ON)}: 0.86 Ω HS + LS at 24 V, 25°C
- High current capacity
 - 1.5-A Full scale per bridge
 - 1.0-A rms per bridge
- Fixed off-time PWM chopping
- Simple STEP/DIR interface
- Low-current sleep mode (20 μA)
- Small package and footprint
 - 24 HTSSOP PowerPAD[™] package
 - 28 WQFN package
- Protection features
 - VM undervoltage lockout (UVLO)
 - Charge pump undervoltage (CPUV)
 - Overcurrent protection (OCP)
 - Thermal shutdown (TSD)
 - Fault condition indication pin (nFAULT)

2 Applications

- Multi-function printers and scanners
- Laser beam printers
- 3D printers
- Automatic teller and money handling machines
- Video security cameras
- Office automation machines
- Factory automation and robotics

3 Description

The DRV8885 is a stepper motor driver for industrial equipment applications. The device has two N-channel power MOSFET H-bridge drivers, a microstepping indexer, and integrated current sense. The DRV8885 is capable of driving up to 1.5 A full scale or 1.0 A rms output current (depending on proper PCB ground plane for thermal dissipation and at 24 V and $T_A = 25^{\circ}$ C).

The DRV8885 integrated current sense functionality eliminates the need for two external sense resistors.

The STEP/DIR pins provide a simple control interface. The device can be configured in full-step up to 1/16 step modes. A low-power sleep mode is provided for very-low quiescent current standby using a dedicated nSLEEP pin.

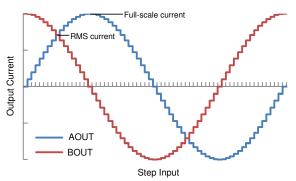
Internal protection functions are provided for undervoltage, charge pump faults, overcurrent, short circuits, and overtemperature. Fault conditions are indicated by an nFAULT pin.

| D | | | | | |
|-------------|-------------|-------------------|--|--|--|
| PART NUMBER | PACKAGE | BODY SIZE (NOM) | | | |
| DRV8885 | HTSSOP (24) | 7.80 mm × 4.40 mm | | | |
| DKV0000 | WQFN (28) | 5.50 mm × 3.5 mm | | | |

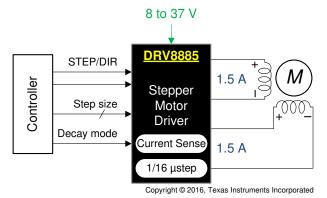
Device Information ⁽¹⁾

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Microstepping Current Waveform



Simplified Schematic



An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

XAS STRUMENTS

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4 Revision History

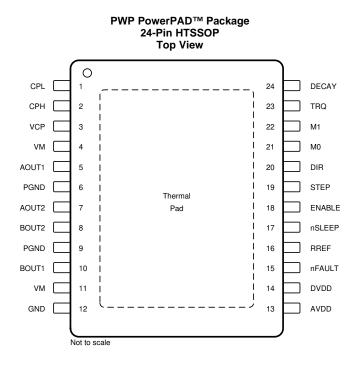
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

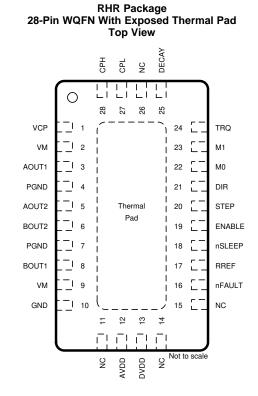
| C | hanges from Revision C (November 2018) to Revision D | Page |
|---|---|------|
| • | Added Various Sources of Error and Application-Specific Error Calculations | 18 |
| C | hanges from Revision B (July 2018) to Revision C | Page |
| • | Changed device status from Advance Information to Production Data | 1 |
| C | hanges from Revision A (April 2016) to Revision B | Page |
| • | Added the WQFN package option | 1 |
| • | Deleted and internal indexer from the description of the ENABLE pin in the Pin Functions table | 3 |
| • | Changed until ENABLE is deasserted to until ENABLE is asserted in the Device Functional Modes section | 31 |
| • | Added the Receiving Notification of Documentation Updates section | 37 |
| С | hanges from Original (October 2015) to Revision A | Page |
| • | Updated peak drive current based on OCP | 4 |
| • | Updated R _{PD} and R _{PU} values | 6 |

Fixed chopping current equation 18 Added "Controlling RREF with a PWM Resource"...... 18



5 Pin Configuration and Functions





Pin Functions

| PIN | | | | | | |
|--------|---------|------|---------------------|--|--|--|
| NAME | NC |). | TYPE ⁽¹⁾ | DESCRIPTION | | |
| NAME | HTSSOP | WQFN | | | | |
| AOUT1 | 5 | 3 | 0 | Winding A output Connect to stopper mater winding | | |
| AOUT2 | 7 | 5 | 0 | Winding A output. Connect to stepper motor winding. | | |
| AVDD | 13 | 12 | PWR | Internal regulator. Bypass to GND with a X5R or X7R, 0.47-µF, 6.3-V ceramic capacitor. | | |
| BOUT1 | 10 | 8 | 0 | Winding Doutput Connect to stopper mater winding | | |
| BOUT2 | 8 | 6 | 0 | Winding B output. Connect to stepper motor winding. | | |
| CPH | 2 | 28 | PWR | | | |
| CPL | PL 1 27 | | PWR | Charge pump switching node. Connect a X5R or X7R, 0.022-µF, VM-rated ceramic capacitor from CPH to CPL. | | |
| DECAY | 24 | 25 | I | Decay-mode setting. Sets the decay mode (see the <i>Decay Modes</i> section). Decay mode can be adjusted during operation. | | |
| DIR | 20 | 21 | I | Direction input. Logic level sets the direction of stepping; internal pulldown resistor. | | |
| DVDD | 14 | 13 | PWR | Internal regulator. Bypass to GND with a X5R or X7R, 0.47-µF, 6.3-V ceramic capacitor. | | |
| ENABLE | 18 | 19 | I | Enable driver input. Logic high to enable device outputs; logic low to disable; internal pulldown resistor. | | |
| GND | 12 | 10 | PWR | Device ground. Connect to system ground. | | |
| M0 | 21 | 22 | | Microstanning mode setting. Sate the stan mode, tri level ning, gate the stan mode, internal nulldown resister | | |
| M1 | 22 | 23 | I | Microstepping mode-setting. Sets the step mode; tri-level pins; sets the step mode; internal pulldown resistor. | | |
| | | 11 | | | | |
| NC | | 14 | | No connect. No internal connection | | |
| NC | _ | 15 | | No connect. No internal connection | | |
| 2 | | 26 | | | | |
| PGND | 6 | 4 | PWR | Dewes around Connect to system around | | |
| PGND 9 | | 7 | FVK | Power ground. Connect to system ground. | | |
| RREF | 16 | 17 | I | Current-limit analog input. Connect a resistor to ground to set full-scale regulation current. | | |

(1) I = input, O = output, PWR = power, OD = open-drain

STRUMENTS

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Pin Functions (continued)

| PIN | | PIN | | |
|--------|--------|------|---------------------|---|
| NAME | NC |). | TYPE ⁽¹⁾ | DESCRIPTION |
| NAME | HTSSOP | WQFN | | |
| STEP | 19 | 20 | I | Step input. A rising edge causes the indexer to advance one step; internal pulldown resistor. |
| TRQ | 23 | 24 | Ι | Current-scaling control. Scales the output current; tri-level pin. |
| VCP | 3 | 1 | PWR | Charge pump output. Connect a X5R or X7R, 0.22-µF, 16-V ceramic capacitor to VM. |
| VM | 4 | 2 | 2 PWR | Power supply. Connect to motor supply voltage and bypass to GND with two 0.01-µF ceramic capacitors (one for |
| VIVI | 11 | 9 | PVVR | each pin) plus a bulk capacitor rated for VM. |
| nFAULT | 15 | 16 | OD | Fault indication. Pulled logic low with fault condition; open-drain output requires an external pullup resistor. |
| nSLEEP | 17 | 18 | Ι | Sleep mode input. Logic high to enable device; logic low to enter low-power sleep mode; internal pulldown resistor. |

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

| | MIN | MAX | UNIT |
|---|------|----------|------|
| Power supply voltage (VM) | -0.3 | 40 | V |
| Power supply voltage ramp rate (VM) | 0 | 2 | V/µs |
| Charge pump voltage (VCP, CPH) | -0.3 | VM + 7 | V |
| Charge pump negative switching pin (CPL) | -0.3 | VM | V |
| Internal regulator voltage (DVDD) | -0.3 | 3.8 | V |
| Internal regulator current output (DVDD) | 0 | 1 | mA |
| Internal regulator voltage (AVDD) | -0.3 | 5.7 | V |
| Control pin voltage (STEP, DIR, ENABLE, nFAULT, M0, M1, DECAY, TRQ, nSLEEP) | -0.3 | 5.7 | V |
| Open drain output current (nFAULT) | 0 | 10 | mA |
| Current limit input pin voltage (RREF) | -0.3 | 6.0 | V |
| Continuous phase node pin voltage (AOUT1, AOUT2, BOUT1, BOUT2) | -0.7 | VM + 0.7 | V |
| Peak drive current (AOUT1, AOUT2, BOUT1, BOUT2) | | 2.3 | А |
| Operating junction temperature, T _J | -40 | 150 | °C |
| Storage temperature, T _{stg} | -65 | 150 | °C |

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

| | | | VALUE | UNIT |
|--|---|---|-------|------|
| V | Electrostatio discharge | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾ | ±2000 | M |
| V _(ESD) Electrostatic discharge | Charged-device model (CDM), per JEDEC specification JESD22-C101 (2) | ±500 | V | |

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

| | | MIN | MAX | UNIT |
|-------------------|-------------------------------|-----|--------------------|------|
| VM | Power supply voltage range | 8 | 37 | V |
| VCC | Logic level input voltage | 0 | 5.3 | V |
| f_{PWM} | Applied STEP signal (STEP) | 0 | 100 ⁽¹⁾ | kHz |
| I _{DVDD} | DVDD external load current | 0 | 1 ⁽²⁾ | mA |
| I _{FS} | Motor full scale current | 0 | 1.5 | А |
| I _{rms} | Motor rms current | 0 | 1.0 | А |
| T _A | Operating ambient temperature | -40 | 125 | °C |

STEP input can operate up to 500 kHz, but system bandwidth is limited by the motor load
 Power dissipation and thermal limits must be observed

6.4 Thermal Information

| | | DRV | 8885 | |
|----------------------|--|--------------|------------|------|
| | THERMAL METRIC ⁽¹⁾ | PWP (HTSSOP) | RHR (WQFN) | UNIT |
| | | 24 PINS | 28 PINS | |
| R_{\thetaJA} | Junction-to-ambient thermal resistance | 36.1 | 33.6 | °C/W |
| $R_{\theta JC(top)}$ | Junction-to-case (top) thermal resistance | 18.3 | 23.8 | °C/W |
| $R_{\theta JB}$ | Junction-to-board thermal resistance | 15.8 | 12.7 | °C/W |
| ΨJT | Junction-to-top characterization parameter | 0.4 | 0.3 | °C/W |
| ΨЈВ | Junction-to-board characterization parameter | 15.7 | 12.6 | °C/W |
| $R_{\theta JC(bot)}$ | Junction-to-case (bottom) thermal resistance | 1.1 | 3.7 | °C/W |

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

6.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------------------|------------------------------------|--|------|----------|------|------|
| POWER \$ | SUPPLIES (VM, DVDD, AVDD) | | | | | |
| VVM | VM operating voltage | | 8 | | 37 | V |
| I _{VM} | VM operating supply current | VM ≈ 8 to 35 V, ENABLE = 1, nSLEEP = 1, No motor load | | 5 | 8 | mA |
| | | $nSLEEP = 0; T_A = 25^{\circ}C$ | | | 20 | • |
| VMQ | VM sleep mode supply current | nSLEEP = 0; $T_A = 125^{\circ}C^{(1)}$ | | | 40 | μA |
| t _{SLEEP} | Sleep time | nSLEEP = 0 to sleep-mode | | 50 | 200 | μS |
| t _{WAKE} | Wake-up time | nSLEEP = 1 to output transition | | 0.85 | 1.5 | ms |
| t _{ON} | Turn-on time | VM > UVLO to output transition | | 0.85 | 1.5 | ms |
| V _{DVDD} | Internal regulator voltage | 0- to 1-mA external load | 2.9 | 3.3 | 3.6 | V |
| V _{AVDD} | Internal regulator voltage | No external load | 4.5 | 5.0 | 5.5 | V |
| CHARGE | PUMP (VCP, CPH, CPL) | | | | | |
| V _{VCP} | VCP operating voltage | VM > 8 V | | VM + 5.5 | | V |
| | EVEL INPUTS (STEP, DIR, ENABL | E, nSLEEP, M1) | | | | |
| V _{IL} | Input logic low voltage | | 0 | | 0.8 | V |
| VIH | Input logic high voltage | | 1.6 | | 5.3 | V |
| V _{HYS} | Input logic hysteresis | | 100 | | | mV |
| | Input logic low current | VIN = 0 V | -1 | | 1 | μA |
| <u></u> I _{IH} | Input logic high current | VIN = 5.0 V | | | 100 | μΑ |
| R _{PD} | Pulldown resistance | To GND | | 100 | | kΩ |
| t _{PD} | Propagation delay | STEP to current change | | | 1.2 | μS |
| | EL INPUT (M0, TRQ) | - | | | | |
| VIL | Tri-level input logic low voltage | | 0 | | 0.65 | V |
| V _{IZ} | Tri-level input Hi-Z voltage | | | 1.1 | | V |
| V _{IH} | Tri-level input logic high voltage | | 1.5 | | 5.3 | V |
| I _{IL} | Tri-level input logic low current | VIN = 0 V | -80 | | | μA |
| I _{IZ} | Tri-level input Hi-Z current | VIN = 1.3 V | -5 | | 5 | μA |
| IIH | Tri-level input logic high current | VIN = 5.0 V | | | 155 | μA |
| R _{PD} | Tri-level pulldown resistance | To GND | 18 | 32 | 50 | kΩ |
| R _{PU} | Tri-level pullup resistance | To DVDD | 30 | 60 | 90 | kΩ |
| | EVEL INPUT (DECAY) | · · · · · · · · · · · · · · · · · · · | | | | |
| V _{I1} | Quad-level input voltage 1 | 5% resistor 5 k Ω to GND | 0.07 | 0.11 | 0.13 | V |
| V _{I2} | Quad-level input voltage 2 | 5% resistor 15 k Ω to GND | 0.24 | 0.32 | 0.40 | V |
| V _{I3} | Quad-level input voltage 3 | 5% resistor 45 k Ω to GND | 0.71 | 0.97 | 1.20 | V |
| V _{I4} | Quad-level input voltage 4 | 5% resistor 135 k Ω to GND | 2.12 | 2.90 | 3.76 | V |
| l _o | Output current | To GND | 14 | 22 | 30 | μA |
| | L OUTPUTS (nFAULT) | 1 | L | | | • |
| V _{OL} | Output logic low voltage | $I_O = 1 \text{ mA}, \text{ R}_{\text{PULLUP}} = 4.7 \text{ k}\Omega$ | | | 0.5 | V |
| I _{OH} | Output logic high leakage | $V_O = 5.0 \text{ V}, \text{ R}_{\text{PULLUP}} = 4.7 \text{ k}\Omega$ | -1 | | +1 | μA |

(1) Not tested in production; limits are based on characterization data

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Electrical Characteristics (continued)

over operating free-air temperature range (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---------------------------------|--------------------------------------|---|--------|----------|-------|------|
| MOTOR DR | IVER OUTPUTS (AOUT1, AOUT | Γ2, BOUT1, BOUT2) | | | | |
| R _{DS(ON)} | High-side FET on resistance | VM = 24 V, I = 1 A, T _A = 25°C | | 440 | 490 | mΩ |
| R _{DS(ON)} | Low-side FET on resistance | VM = 24 V, I = 1 A, T _A = 25°C | | 420 | 460 | mΩ |
| RISE (2) | Output rise time | | | 100 | | ns |
| FALL ⁽²⁾ | Output fall time | | | 100 | | ns |
| DEAD ⁽²⁾ | Output dead time | | | 200 | | ns |
| V _d ⁽²⁾ | Body diode forward voltage | I _{OUT} = 0.5 A | | 0.7 | 1.0 | V |
| WM CURF | RENT CONTROL (RREF) | - | | | | |
| ARREF | RREF transimpedance gain | | 28.1 | 30 | 31.9 | kAΩ |
| / _{RREF} | RREF voltage | RREF = 18 to 132 kΩ | 1.18 | 1.232 | 1.28 | V |
| OFF | PWM off-time | | | 20 | | μS |
| CRREF | Equivalent capacitance on RREF | | | | 10 | pF |
| | PWM blanking time | I _{RREF} = 1.5 A, 63% to 100% current setting | | 1.5 | | μs |
| BLANK | | I _{RREF} = 1.5 A, 0% to 63% current setting | | 1.0 | | |
| | | I _{RREF} = 1.0 A, 10% to 20% current setting, 1% reference resistor | -25% | | 25% | |
| ∆I _{TRIP} | Current trip accuracy | I _{RREF} = 1.0 A, 20% to 63% current setting, 1% reference resistor | -12.5% | | 12.5% | |
| | | I _{RREF} = 1.0 A, 71% to 100% current setting, 1% reference resistor | -6.25% | | 6.25% | |
| PROTECTIO | ON CIRCUITS | · · · · · · | | | | |
| , | | VM falling; UVLO report | | | 7.8 | |
| / _{UVLO} | VM UVLO | VM rising; UVLO recovery | | | 8.0 | V |
| / _{UVLO,HYS} | Undervoltage hysteresis | Rising to falling threshold | | 100 | | mV |
| V _{CPUV} | Charge pump undervoltage | VCP falling; CPUV report | | VM + 2.0 | | V |
| OCP | Overcurrent protection trip level | Current through any FET | 2.3 | | | А |
| OCP | Overcurrent deglitch time | | 1.3 | 1.9 | 2.8 | μS |
| RETRY | Overcurrent retry time | | 1 | | 1.6 | ms |
| r _{tsd} ⁽²⁾ | Thermal shutdown temperature | Die temperature T _J | 150 | | | °C |
| T _{HYS} ⁽²⁾ | Thermal shutdown hysteresis | Die temperature TJ | | 20 | | °C |

(2) Not tested in production; limits are based on characterization data

6.6 Indexer Timing Requirements

 $T_A = 25^{\circ}C$, over recommended operating conditions unless otherwise noted

| NO. | | | MIN | IAX UNIT |
|-----|--------------------------|--|-----|----------------------|
| 1 | fstep | Step frequency | 50 | 0 ⁽¹⁾ kHz |
| 2 | t _{WH(STEP)} | Pulse duration, STEP high | 970 | ns |
| 3 | t _{WL(STEP)} | Pulse duration, STEP low | 970 | ns |
| 4 | t _{SU(DIR, Mx)} | Setup time, DIR or USMx to STEP rising | 200 | ns |
| 5 | t _{H(DIR, Mx)} | Hold time, DIR or USMx to STEP rising | 200 | ns |

(1) STEP input can operate up to 500 kHz, but system bandwidth is limited by the motor load

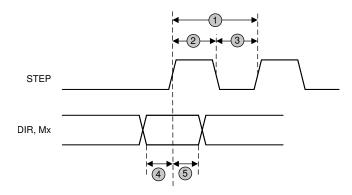
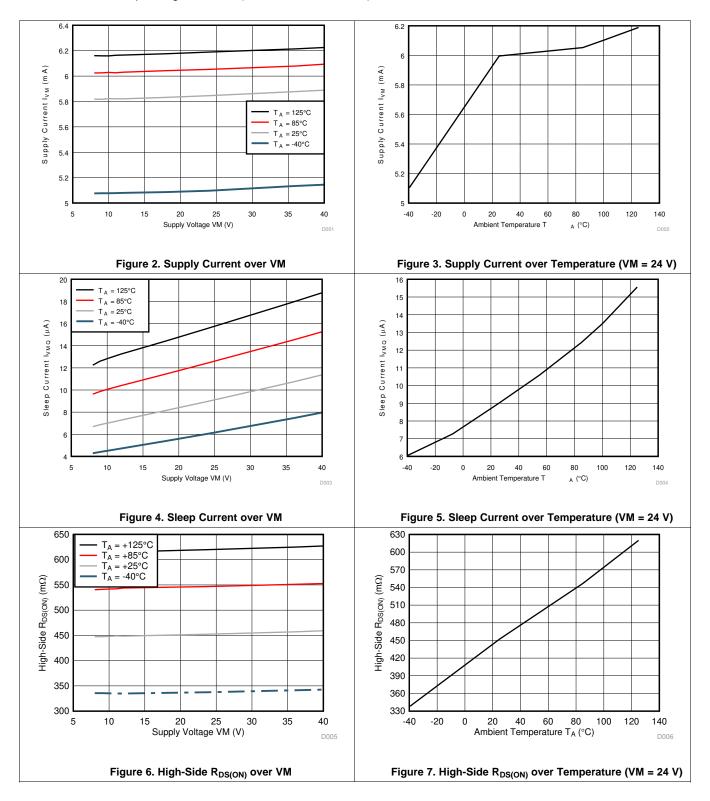


Figure 1. Timing Diagram



6.7 Typical Characteristics

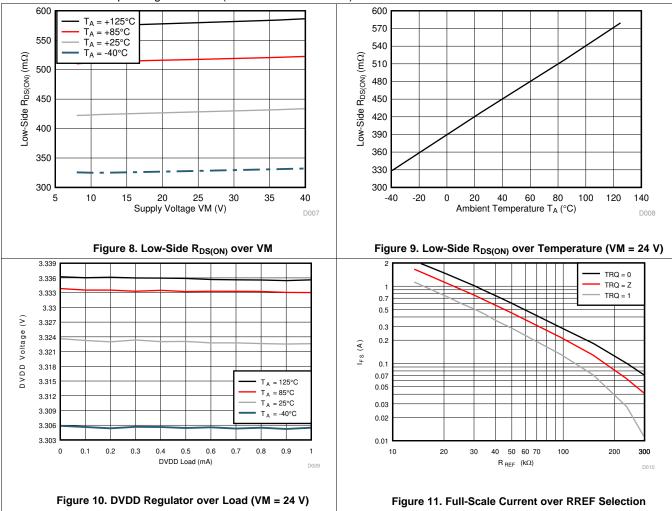
Over recommended operating conditions (unless otherwise noted)





Typical Characteristics (continued)

Over recommended operating conditions (unless otherwise noted)





7 Detailed Description

7.1 Overview

The DRV8885 is an integrated motor driver solution for bipolar stepper motors. The device integrates two NMOS H-bridges, integrated current sense and regulation circuitry, and a microstepping indexer. The DRV8885 can be powered with a supply voltage between 8 and 37 V, and is capable of providing an output current up 2.3-A peak, 1.5-A full-scale, or 1.0-A rms. Actual full-scale and rms current will depend on ambient temperature, supply voltage, and PCB ground plane size.

The DRV8885 integrates current sense functionality, which eliminates the need for high-power external sense resistors. This integration does not dissipate the external sense resistor power, because the current sense functionality is not implemented using a resistor-based architecture. This functionality helps improve component cost, board size, PCB layout, and system power consumption.

A simple STEP/DIR interface allows easy interfacing to the controller circuit. The internal indexer is able to execute high-accuracy microstepping without requiring the processor to control the current level. The indexer is capable of full step and half step as well as microstepping to 1/4, 1/8, and 1/16. In addition to the standard half stepping mode, a non-circular 1/2-stepping mode is available for increased torque output at higher motor rpm.

The current regulation is configurable with several decay modes of operation. The decay mode can be selected as a fixed slow, slow/mixed, or mixed decay. The slow/mixed decay mode uses slow decay on increasing steps and mixed decay on decreasing steps.

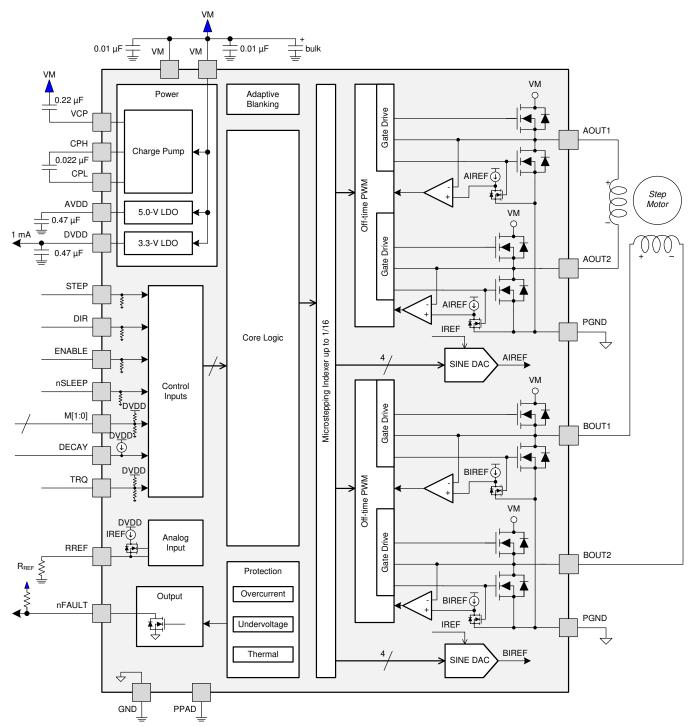
An adaptive blanking time feature automatically scales the minimum drive time with output current. This helps alleviate zero-crossing distortion by limiting the drive time at low-current steps.

A torque DAC feature allows the controller to scale the output current without needing to scale the reference resistor. The torque DAC is accessed using a digital input pin. This allows the controller to save power by decreasing the current consumption when not high current is not required.

A low-power sleep mode is included which allows the system to save power when not driving the motor.



7.2 Functional Block Diagram



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7.3 Feature Description

Table 1 lists the recommended external components for the DRV8885 device.

| COMPONENT | PIN 1 | PIN 2 | RECOMMENDED | | |
|---------------------|--------------------|--------|---|--|--|
| C _{VM} | VM | GND | Two 0.01-µF ceramic capacitors rated for VM | | |
| C _{VM} | VM | GND | Bulk electrolytic capacitor rated for VM | | |
| C _{VCP} | VCP | VM | 16-V, 0.22-µF ceramic capacitor | | |
| C _{SW} | CPH | CPL | 0.022-µF X7R capacitor rated for VM | | |
| C _{AVDD} | AVDD | GND | 6.3-V, 0.47-µF ceramic capacitor | | |
| C _{DVDD} | DVDD | GND | 6.3-V, 0.47-µF ceramic capacitor | | |
| R _{nFAULT} | VCC ⁽¹⁾ | nFAULT | >4.7 kΩ | | |
| R _{REF} | RREF | GND | Resistor to limit chopping current must be installed. See the <i>Typical Application</i> section for value selection. | | |

Table 1. External Components

(1) VCC is not a pin on the DRV8885, but a VCC supply voltage pullup is required for open-drain output nFAULT; nFAULT may be pulled up to DVDD

7.3.1 Stepper Motor Driver Current Ratings

Stepper motor drivers can be classified using three different numbers to describe the output current: peak, rms, and full-scale.

7.3.1.1 Peak Current Rating

The peak current in a stepper driver is limited by the overcurrent protection trip threshold I_{OCP} . The peak current describes any transient duration current pulse, for example when charging capacitance, when the overall duty cycle is very low. In general the minimum value of I_{OCP} specifies the peak current rating of the stepper motor driver. For the DRV8885, the peak current rating is 2.3 A per bridge.

7.3.1.2 RMS Current Rating

The rms (average) current is determined by the thermal considerations of the IC. The rms current is calculated based on the R_{DS(ON)}, rise and fall time, PWM frequency, device quiescent current, and package thermal performance in a typical system at 25°C. The real operating rms current may be higher or lower depending on heatsinking and ambient temperature. For the DRV8885, the rms current rating is 1.0 A per bridge.

7.3.1.3 Full-Scale Current Rating

The full-scale current describes the top of the sinusoid current waveform while microstepping. Since the sineusoid amplitude is related to the rms current, the full-scale current is also determined by the thermal considerations of the IC. The full-scale current rating is approximately $\sqrt{2} \times I_{rms}$. The full-scale current is set by VREF, the sense resistor, and Torque DAC when configuring the DRV8885, see *Current Regulation* for details. For the DRV8885, the full-scale current rating is 1.5 A per bridge.

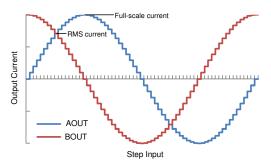


Figure 12. Full-Scale and rms Current

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7.3.2 PWM Motor Drivers

The DRV8885 contains drivers for two full H-bridges. Figure 13 shows a block diagram of the circuitry.

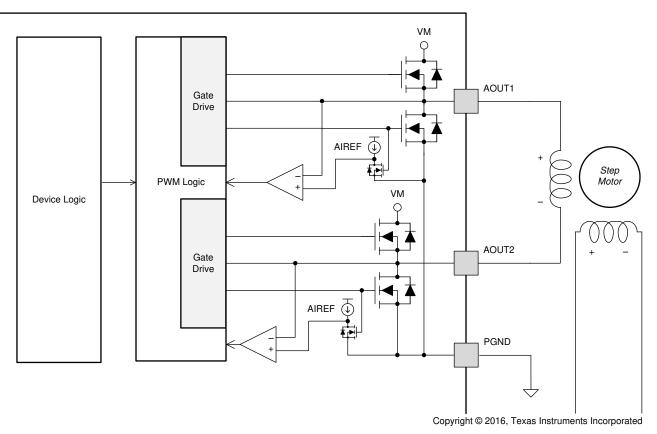


Figure 13. PWM Motor Driver Block Diagram

7.3.3 Microstepping Indexer

Built-in indexer logic in the DRV8885 allows a number of different stepping configurations. The Mx pins are used to configure the stepping format as shown in Table 2.

| M1 | MO | STEP MODE |
|----|----|---|
| 0 | 0 | Full step (2-phase excitation) with 71% current |
| 0 | 1 | 1/16 step |
| 1 | 0 | 1/2 step |
| 1 | 1 | 1/4 step |
| 0 | Z | 1/8 step |
| 1 | Z | Non-circular 1/2 step |

Table 3 shows the relative current and step directions for full-step through 1/16-step operation. The AOUT current is the sine of the electrical angle; BOUT current is the cosine of the electrical angle. Positive current is defined as current flowing from xOUT1 to xOUT2 while driving.

At each rising edge of the STEP input the indexer travels to the next state in the table. The direction is shown with the DIR pin logic high. If the DIR pin is logic low, the sequence is reversed.

On power-up or when exiting sleep mode, keep the STEP pin logic low, otherwise the indexer will advance one step.



Note that if the step mode is changed from full, $\frac{1}{2}$, $\frac{1}{4}$, 1/8, or 1/16 to full, $\frac{1}{2}$, $\frac{1}{4}$, 1/8, or 1/16 while stepping, the indexer will advance to the next valid state for the new MODE setting at the rising edge of STEP. If the step mode is changed from or to non-circular $\frac{1}{2}$ step the indexer will go immediately to the valid state for that mode.

The home state is an electrical angle of 45°. This state is entered after power-up, after exiting logic undervoltage lockout, or after exiting sleep mode. This is shown in the table below with cells outlined in red.

| FULL STEP | 1/2 STEP | 1/4 STEP | 1/8 STEP | 1/16 STEP | ELECTRICAL ANGLE (DEGREES) | AOUT CURRENT (% FULL-SCALE) | BOUT CURRENT (% FULL-SCALE) |
|-----------|----------|----------|----------|-----------|----------------------------------|-----------------------------------|-----------------------------------|
| | 1 | 1 | 1 | 1 | 0.000° | 0% | 100% |
| | | | | 2 | 5.625° | 10% | 100% |
| | | | 2 | 3 | 11.250° | 20% | 98% |
| | | | | 4 | 16.875° | 29% | 96% |
| | | 2 | 3 | 5 | 22.500° | 38% | 92% |
| | | | | 6 | 28.125° | 47% | 88% |
| | | | 4 | 7 | 33.750° | 56% | 83% |
| | | | | 8 | 39.375° | 63% | 77% |
| 1 | 2 | 3 | 5 | 9 | 45.000° | 71% | 71% |
| | | | | 10 | 50.625° | 77% | 63% |
| | | | 6 | 11 | 56.250° | 83% | 56% |
| | | | | 12 | 61.875° | 88% | 47% |
| | | 4 | 7 | 13 | 67.500° | 92% | 38% |
| | | | | 14 | 73.125° | 96% | 29% |
| | | | 8 | 15 | 78.750° | 98% | 20% |
| | | | | 16 | 84.375° | 100% | 10% |
| | 3 | 5 | 9 | 17 | 90.000° | 100% | 0% |
| | | | | 18 | 95.625° | 100% | -10% |
| | | | 10 | 19 | 101.250° | 98% | -20% |
| | | | | 20 | 106.875° | 96% | -29% |
| | | 6 | 11 | 21 | 112.500° | 92% | -38% |
| | | | | 22 | 118.125° | 88% | -47% |
| | | | 12 | 23 | 123.750° | 83% | -56% |
| | | | | 24 | 129.375° | 77% | -63% |
| 2 | 4 | 7 | 13 | 25 | 135.000° | 71% | -71% |
| | | | | 26 | 140.625° | 63% | -77% |
| | | | 14 | 27 | 146.250° | 56% | -83% |
| | | | | 28 | 151.875° | 47% | -88% |
| | | 8 | 15 | 29 | 157.500° | 38% | -92% |
| | | | | 30 | 163.125° | 29% | -96% |
| | | | 16 | 31 | 168.750° | 20% | -98% |
| | | | | 32 | 174.375° | 10% | -100% |
| | 5 | 9 | 17 | 33 | 180.000° | 0% | -100% |
| | | | | 34 | 185.625° | -10% | -100% |
| | | | 18 | 35 | 191.250° | -20% | -98% |
| | | | | 36 | 196.875° | -29% | -96% |
| | | 10 | 19 | 37 | 202.500° | -38% | -92% |
| | | | | 38 | 208.125° | -47% | -88% |
| | | | 20 | 39 | 213.750° | -56% | -83% |
| | | | | 40 | 219.375° | -63% | -77% |

Table 3. Microstepping Relative Current Per Step (DIR = 1)

| | XAS ISTRUMENTS |
|--|-------------------|
|--|-------------------|

| FULL STEP | 1/2 STEP | 1/4 STEP | 1/8 STEP | 1/16 STEP | ELECTRICAL ANGLE (DEGREES) | AOUT CURRENT (% FULL-SCALE) | BOUT CURRENT (% FULL-SCALE) |
|-----------|----------|----------|----------|-----------|----------------------------------|-----------------------------------|-----------------------------------|
| 3 | 6 | 11 | 21 | 41 | 225.000° | -71% | -71% |
| | | | | 42 | 230.625° | -77% | -63% |
| | | | 22 | 43 | 236.250° | -83% | -56% |
| | | | | 44 | 241.875° | -88% | -47% |
| | | 12 | 23 | 45 | 247.500° | -92% | -38% |
| | | | | 46 | 253.125° | -96% | -29% |
| | | | 24 | 47 | 258.750° | -98% | -20% |
| | | | | 48 | 264.375° | -100% | -10% |
| | 7 | 13 | 25 | 49 | 270.000° | -100% | 0% |
| | | | | 50 | 275.625° | -100% | 10% |
| | | | 26 | 51 | 281.250° | -98% | 20% |
| | | | | 52 | 286.875° | -96% | 29% |
| | | 14 | 27 | 53 | 292.500° | -92% | 38% |
| | | | | 54 | 298.125° | -88% | 47% |
| | | | 28 | 55 | 303.750° | -83% | 56% |
| | | | | 56 | 309.375° | -77% | 63% |
| 4 | 8 | 15 | 29 | 57 | 315.000° | -71% | 71% |
| | | | | 58 | 320.625° | -63% | 77% |
| | | | 30 | 59 | 326.250° | -56% | 83% |
| | | | | 60 | 331.875° | -47% | 88% |
| | | 16 | 31 | 61 | 337.500° | -38% | 92% |
| | | | | 62 | 343.125° | -29% | 96% |
| | | | 32 | 63 | 348.750° | -20% | 98% |
| | | | | 64 | 354.375° | -10% | 100% |
| | 1 | 1 | 1 | 1 | 360.000° | 0% | 100% |

Table 3. Microstepping Relative Current Per Step (DIR = 1) (continued)

Non-circular 1/2–step operation is shown below. This stepping mode consumes more power than circular ½-step operation, but provides a higher torque at high motor rpm.

Table 4. Non-Circular 1/2-Stepping Current

| NON-CIRCULAR 1/2 STEP | AOUT CURRENT (% FULL-SCALE) | BOUT CURRENT (% FULL-SCALE) | ELECTRICAL ANGLE (DEGREES) |
|-----------------------|--------------------------------|--------------------------------|-------------------------------|
| 1 | 0 | 100 | 0 |
| 2 | 100 | 100 | 45 |
| 3 | 100 | 0 | 90 |
| 4 | 100 | -100 | 135 |
| 5 | 0 | -100 | 180 |
| 6 | -100 | -100 | 225 |
| 7 | -100 | 0 | 270 |
| 8 | -100 | 100 | 315 |



7.3.4 Current Regulation

The current through the motor windings is regulated by an adjustable fixed-off-time PWM current regulation circuit. When an H-bridge is enabled, current rises through the winding at a rate dependent on the DC voltage, inductance of the winding, and the magnitude of the back EMF present. Once the current hits the current chopping threshold, the bridge enters a decay mode for a fixed, 20 μ s, period of time to decrease the current. After the off time expires, the bridge is re-enabled, starting another PWM cycle.

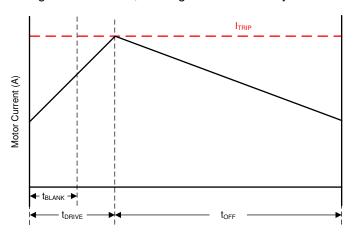


Figure 14. Current Chopping Waveform

The PWM chopping current is set by a comparator which looks at the voltage across current sense FETs in parallel with the low-side drivers. The current sense FETs are biased with a reference current that is the output of a current-mode sine-weighted DAC whose full-scale reference current is set by the current through the RREF pin. An external resistor is placed from the RREF pin to GND in order to set the reference current. In addition, the TRQ pin can further scale the reference current.

The chopping current is calculated as follows:

$$I_{FS} (A) = \frac{A_{RREF} (kA\Omega)}{RREF (k\Omega)} \times TRQ (\%) = \frac{30 (kA\Omega)}{RREF (k\Omega)} \times TRQ (\%)$$

(1)

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Example: If a 30-kΩ resistor is connected to the RREF pin, the chopping current will be 1 A (TRQ at 100%)

The TRQ pin is the input to a DAC used to scale the output current. The current scalar value for different inputs is shown below.

| • | • |
|-----|----------------------|
| TRQ | CURRENT SCALAR (TRQ) |
| 0 | 100% |
| Z | 75% |
| 1 | 50% |

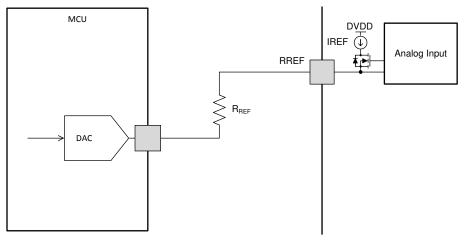
Table 5. Torque DAC Settings



7.3.5 Controlling RREF With an MCU

In some cases, the full-scale output current may need to be changed on the fly between many different values, depending on motor speed and loading. The RREF pin reference current can be adjusted in system by tying the RREF resistor to a DAC output instead of GND.

In this mode of operation, as the DAC voltage increases, the reference current will decrease and therefore the full-scale current will decrease as well. For proper operation, the output of the DAC should not rise above V_{RREF} .



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Figure 15. Controlling RREF with a DAC

The chopping current as controlled by a DAC is calculated as follows:

$$I_{FS} (A) = \frac{A_{RREF} (kA\Omega) \times \left[V_{RREF} (V) - V_{DAC} (V) \right]}{V_{RREF} (V) \times RREF (k\Omega)} \times TRQ (\%)$$
(2)

Example: If a 20-k Ω resistor is connected from the RREF pin to the DAC, and the DAC is outputting 0.74 V, the chopping current will be 600 mA (TRQ at 100%)

RREF can also be adjusted using a PWM signal and low-pass filter.

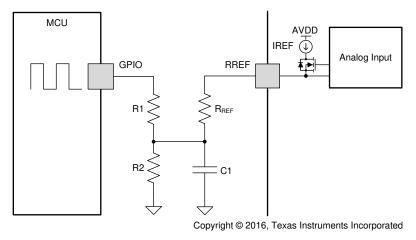


Figure 16. Controlling RREF with a PWM Resource

7.3.5.1 Various Sources of Error

When performing a design error calculation, the different variables that contribute the most to the error must be considered. To do so, first consider the typical values extracted from DRV8885 data sheet which are listed in Table 6 with a 20-k Ω 1% resistor.

| Parameter | Minimum | Typical | Maximum |
|-------------------|---------|---------|---------|
| A _{RREF} | 28100 | 30000 | 31900 |
| V _{RREF} | 1.18 | 1.232 | 1.28 |
| RREF | 19800 | 20000 | 20200 |

Table 6. DRV8885 Data Sheet Values

Using and knowing the desired output current, the V_{DAC} value can be obtained. For example, the DRV8885EVM, which has a 20-k Ω resistor for RREF, was selected to operate at a 1-A, 400mA, and 200 mA current. Table 7 lists the calculated V_{DAC} values using typical A_{RREF} and V_{RREF} data sheet values

| Parameter | Minimum | Typical | Maximum | | |
|-------------------|---------|---------|---------|--|--|
| I _{FS} | 1 | 0.4 | 0.2 | | |
| A _{RREF} | 30 000 | 30 000 | 30 000 | | |
| V _{RREF} | 1.232 | 1.232 | 1.232 | | |
| R _{REF} | 20 000 | 20 000 | 20 000 | | |
| V _{DAC} | 0.4107 | 0.9035 | 1.0677 | | |

Table 7. V_{DAC} Calculation

Next, use Equation 3 and Equation 4 to calculate the worst case value for the minimum and maximum full scale current, respectively.

$$I_{FSmin} (A) = \frac{A_{RREFmin} (kA\Omega) \times [V_{RREFmin} (V) - V_{DACmax} (V)]}{V_{RREFmin} (V) \times RREF_{max} (k\Omega)} \times TRQ (\%)$$

$$I_{FSmax} (A) = \frac{A_{RREFmax} (kA\Omega) \times [V_{RREFmax} (V) - V_{DACmin} (V)]}{V_{RREFmax} (V) \times RREF_{min} (k\Omega)} \times TRQ (\%)$$
(3)
(4)

These two equations show that error contributions come from V_{DAC} , A_{RREF} , V_{RREF} , and RREF. The next sections will show how these different error contributors, affect the overall I_{FS} error and how they can be improved.

7.3.5.1.1 V_{RREF}, A_{RREF}, and RREF Error

To observe how V_{RREF} , A_{RREF} , and $RREFV_{RREF}$ affect the I_{FS} error , Equation 3 and Equation 4 are used with the data sheet values from earlier while V_{DAC} voltage remains constant. Table 8, Table 9, and Table 10 list the results at different current levels (1 A, 400 mA, and 200 mA, respectively).

| Parameter | Minimum | Typical | Maximum |
|----------------------|---------|---------|---------|
| V _{DAC} | 0.4107 | 0.4107 | 0.4107 |
| A _{RREF} | 28100 | 30000 | 31900 |
| V _{RREF} | 1.18 | 1.232 | 1.28 |
| R _{REF} | 19800 | 20000 | 20200 |
| I _{FS} (mA) | 906.95 | 1000 | 1094.21 |
| Error (%) | -9.30 | | 9.42 |

Table 8. Worst Case Calculation—I_{FS} Error at 1 A

| Parameter | Minimum | Typical | Maximum |
|----------------------|---------|---------|---------|
| V _{DAC} | 0.9035 | 0.9035 | 0.9035 |
| A _{RREF} | 28100 | 30000 | 31900 |
| V _{RREF} | 1.18 | 1.232 | 1.28 |
| R _{REF} | 19800 | 20000 | 20200 |
| I _{FS} (mA) | 326.00 | 400 | 473.93 |
| Error (%) | -18.50 | | 18.48 |

| | | 15 | |
|----------------------|---------|---------|---------|
| Parameter | Minimum | Typical | Maximum |
| V _{DAC} | 1.0677 | 1.0677 | 1.0677 |
| A _{RREF} | 28100 | 30000 | 31900 |
| V _{RREF} | 1.18 | 1.232 | 1.28 |
| R _{REF} | 19800 | 20000 | 20200 |
| I _{FS} (mA) | 135.35 | 200 | 267.18 |
| Error (%) | -33.83 | | 33.59 |

Table 10. Worst Case Calculation—I_{FS} Error at 200 mA

These tables show that as the I_{FS} current level decreases, the overall error percentage increases due to increasing offset error from the internal signal chain. It is worthy to clarify that the V_{RREF} and A_{RREF} values in these tables are data sheet values which represent the characterization data variation across a wide range of temperatures and voltages with additional margin. For information on how to further minimize this percentage of error based on targeted characterization data for V_{RREF} and A_{RREF} , see Application-Specific Error Calculations.

7.3.5.1.2 V_{DAC} Error

Using the same methodology along with Equation 3 and Equation 4, the V_{DAC} error contribution to I_{FS} can be shown. This is done by removing the error from V_{RREF} , A_{RREF} , and RREF. The following examples show the V_{DAC} error value with a 3% and 10% variation.

| 10 | | | |
|---------|---|---|--|
| Minimum | Typical | Maximum | |
| | | | |
| 0.3983 | 0.4107 | 0.423 | |
| 30000 | 30000 | 30000 | |
| 1.232 | 1.232 | 1.232 | |
| 20000 | 20000 | 20000 | |
| 985.08 | 1000 | 1015.07 | |
| -1.50 | | 1.50 | |
| | | | |
| 0.3696 | 0.4107 | 0.4517 | |
| 30000 | 30000 | 30000 | |
| 1.232 | 1.232 | 1.232 | |
| 20000 | 20000 | 20000 | |
| 950.08 | 1000 | 1050.07 | |
| -5.00 | | 5.00 | |
| | 0.3983 30000 1.232 20000 985.08 -1.50 0.3696 30000 1.232 20000 950.08 | 0.3983 0.4107 30000 30000 1.232 1.232 20000 20000 985.08 1000 -1.50 - 0.3696 0.4107 30000 30000 1.232 1.232 20000 20000 950.08 1000 | |

Table 11. Worst Case Calculation—V_{DAC} 3% and 10%, $I_{FS} \; Error \; at 1 \; A$

Table 12. Worst Case Calculation—V_{DAC} 3% and 10%, I_{FS} Error at 400 mA

| _ | 10 | | | |
|----------------------|---------|---------|---------|--|
| Parameter | Minimum | Typical | Maximum | |
| 3% ERROR | | | | |
| V _{DAC} | 0.8764 | 0.9035 | 0.9306 | |
| A _{RREF} | 30000 | 30000 | 31 900 | |
| V _{RREF} | 1.232 | 1.232 | 1.232 | |
| R _{REF} | 20000 | 20000 | 20000 | |
| I _{FS} (mA) | 367.18 | 400 | 433.17 | |
| Error (%) | -8.25 | | 8.25 | |
| 10% ERROR | | | | |
| V _{DAC} | 0.8131 | 0.9035 | 0.9938 | |
| A _{RREF} | 30000 | 30000 | 30000 | |

Table 12. Worst Case Calculation—V_{DAC} 3% and 10%, I_{FS} Error at 400 mA (continued)

| Parameter | Minimum | Typical | Maximum |
|----------------------|---------|---------|---------|
| V _{RREF} | 1.232 | 1.232 | 1.232 |
| R _{REF} | 20000 | 20000 | 20000 |
| I _{FS} (mA) | 290.19 | 400 | 510.16 |
| Error (%) | -27.48 | | 27.48 |

Table 13. Worst Case Calculation—V_{DAC} 3% and 10%, I_{FS} Error at 200 mA

| Parameter | Minimum | Typical | Maximum | |
|----------------------|---------|---------|---------|--|
| 3% ERROR | | | | |
| V _{DAC} | 1.0357 | 1.0677 | 1.0998 | |
| A _{RREF} | 30000 | 30000 | 30000 | |
| V _{RREF} | 1.232 | 1.232 | 1.232 | |
| R _{REF} | 20000 | 20000 | 20000 | |
| I _{FS} (mA) | 161.22 | 200 | 239.20 | |
| Error (%) | -19.48 | | 19.48 | |
| 10% ERROR | | | | |
| V _{DAC} | 0.9610 | 1.0677 | 1.1745 | |
| A _{RREF} | 30000 | 30000 | 30000 | |
| V _{RREF} | 1.232 | 1.232 | 1.232 | |
| R _{REF} | 20000 | 20000 | 20000 | |
| I _{FS} (mA) | 70.23 | 200 | 330.19 | |
| Error (%) | -64.92 | | 64.92 | |

These tables show that as the variation in V_{DAC} increases, the error percentage increases. Also, for very low currents, the error percentage increases greatly because of the V_{DAC} proximity to the V_{RREF} voltage.

7.3.5.2 Application-Specific Error Calculations

As described in the previous analysis, it is possible to obtain a tighter error calculations by using values for V_{RREF} and A_{RREF} for the specific application use case. The data sheet parameters represent limits based on design and characterization data across a wide range of temperatures and voltage with additional margin. For the following example, the operational voltage is limited to V_{VM} = 24 V, a common operating point for the DRV8884, DRV8885, DRV8886, and DRV8886AT.

Considering this use case, Table 14 provides updated values for V_{RREF} and A_{RREF}.

Table 14. Values For DRV8885 V_{VM}= 24-V

| Parameter | Minimum | Typical | Maximum | |
|-------------------|---------|---------|---------|--|
| A _{RREF} | 28800 | 30000 | 31200 | |
| V _{RREF} | 1.207 | 1.232 | 1.257 | |
| RREF | 19800 | 20000 | 20200 | |

Using values above and maintaining V_{DAC} constant, the error percentage is reduced as shown in the following tables.

| Parameter | Minimum | Typical | Maximum |
|-------------------|---------|---------|---------|
| V _{DAC} | 0.4107 | 0.4107 | 0.4107 |
| A _{RREF} | 28800 | 30000 | 31200 |
| V _{RREF} | 1.207 | 1.232 | 1.257 |
| R _{REF} | 19800 | 20000 | 20200 |

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| Table 15. I _{FS} Error at 1 A, V _{DAC} Fixed and Application Values (continued) | | | | | |
|---|--------|------|--------|--|--|
| Parameter Minimum Typical Maximum | | | | | |
| I _{FS} (mA) | 940.79 | 1000 | 1060.8 | | |
| Error (%) | -5.93 | | 6.07 | | |

Table 16. I_{FS} Error at 400 mA, V_{DAC} Fixed and Application Values

| Parameter | Minimum | Typical | Maximum |
|----------------------|---------|---------|---------|
| V _{DAC} | 0.9035 | 0.9035 | 0.9035 |
| A _{RREF} | 28800 | 30000 | 31200 |
| V _{RREF} | 1.207 | 1.232 | 1.257 |
| R _{REF} | 19800 | 20000 | 20200 |
| I _{FS} (mA) | 358.54 | 400 | 443.18 |
| Error (%) | -10.4 | | 10.75 |

Table 17. I_{FS} Error at 200 mA, V_{DAC} Fixed and Application Values

| Parameter | Minimum | Typical | Maximum |
|----------------------|---------|---------|---------|
| V _{DAC} | 1.0677 | 1.0677 | 1.0677 |
| A _{RREF} | 28800 | 30000 | 31200 |
| V _{RREF} | 1.207 | 1.232 | 1.257 |
| R _{REF} | 19800 | 20000 | 20200 |
| I _{FS} (mA) | 164.51 | 200 | 267.26 |
| Error (%) | -17.83 | | 18.51 |

By keeping V_{DAC} value fixed or close to be fixed, yields much less error variation. The same calculation can be made using a V_{DAC} value with a ±3 % variation to compare error percentage difference as shown in the following tables.

Table 18. V_{DAC} 3%, V_{RREF} and A_{RREF} for 24-V Application at 1 A

| Parameter | Minimum | Typical | Maximum |
|----------------------|---------|---------|---------|
| V _{DAC} | 0.3983 | 0.4107 | 0.4230 |
| A _{RREF} | 28800 | 30000 | 31200 |
| V _{RREF} | 1.207 | 1.232 | 1.257 |
| R _{REF} | 19800 | 20000 | 20200 |
| I _{FS} (mA) | 926.09 | 1000 | 1076.39 |
| Error (%) | -7.4 | | 7.63 |

Table 19. V_{DAC} 3%, V_{RREF} and A_{RREF} for 24-VApplication at 400 mA

| Parameter | Minimum | Typical | Maximum |
|----------------------|---------|---------|---------|
| V _{DAC} | 0.8764 | 0.9035 | 0.9306 |
| A _{RREF} | 28800 | 30000 | 31200 |
| V _{RREF} | 1.207 | 1.232 | 1.257 |
| R _{REF} | 19800 | 20000 | 20200 |
| I _{FS} (mA) | 326.52 | 400 | 477.16 |
| Error (%) | -18.41 | | 19.24 |

| Table 20. | V _{DAC} 3% | , V _{RREF} an | d A _{RREF} | for 24-V |
|-----------|---------------------|------------------------|---------------------|----------|
| | Applica | tion at 20 | 0 mÄ | |

| Parameter | Minimum | Typical | Maximum |
|----------------------|---------|---------|---------|
| V _{DAC} | 1.0357 | 1.0677 | 1.0998 |
| A _{RREF} | 28800 | 30000 | 31200 |
| V _{RREF} | 1.207 | 1.232 | 1.257 |
| R _{REF} | 19800 | 20000 | 20200 |
| I _{FS} (mA) | 126.67 | 200 | 277.42 |
| Error (%) | -36.73 | | 38.56 |

Table 18, Table 19, and Table 20 show values closer to the typical values for both V_{DAC} , A_{RREF} , and V_{RREF} . From all these calculations, the error percentages for the 200 mA current are higher because at those very low values, the minimum change greatly affects the full current equation. One method to improve the low-value current accuracy is to use a combination of the MCU DAC and TRQ pin. This method can help improve the error by reducing the need to use only the DAC voltage to achieve the low full-scale current. An example of this method is to achieve 200 mA using the 400 mA DAC setting and the 50% TRQ setting.

7.3.6 Decay Modes

The DRV8885 decay mode is selected by setting the quad-level DECAY pin to the voltage range in Table 21.

| DECAY | INCREASING STEPS | DECREASING STEPS | | | |
|---------------------------------|-----------------------|-----------------------|--|--|--|
| 100 mV Can be tied to ground | Slow decay | Mixed decay: 30% fast | | | |
| 300 mV, 15 k Ω to GND | Mixed decay: 30% fast | Mixed decay: 30% fast | | | |
| 1.0 V, 45 kΩ to GND | Mixed decay: 60% fast | Mixed decay: 60% fast | | | |
| 2.9 V Can be tied to DVDD | Slow decay | Slow decay | | | |

Increasing and decreasing current are defined in the chart below. For the Slow/Mixed decay mode, the decay mode is set as slow during increasing current steps and mixed decay during decreasing current steps. In full step mode the decreasing steps decay mode is always used.

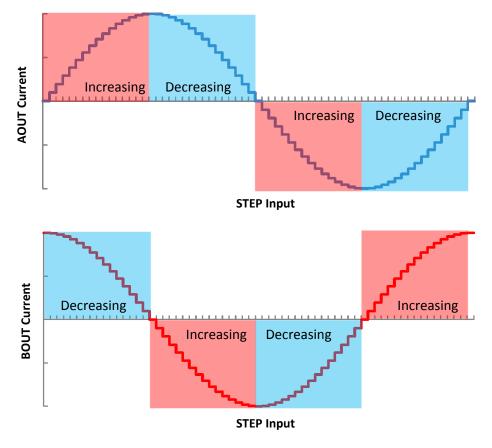
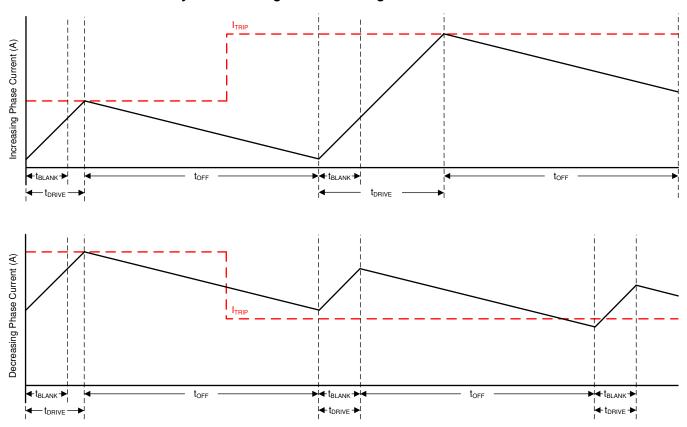


Figure 17. Definition of Increasing and Decreasing Steps



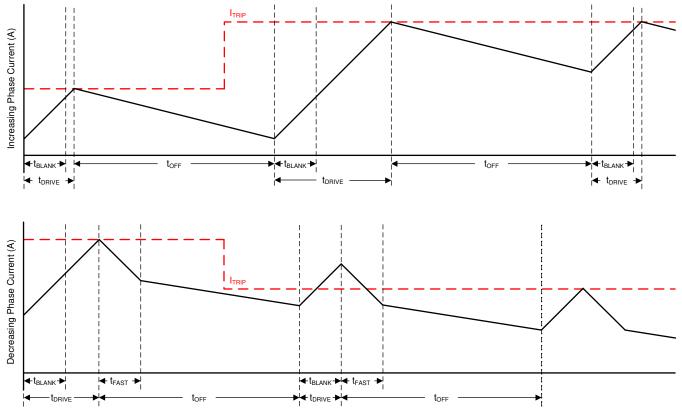


7.3.6.1 Mode 1: Slow Decay for Increasing and Decreasing Current

Figure 18. Slow/Slow Decay Mode

During slow decay, both of the low side FETs of the H-bridge are turned on, allowing the current to be recirculated.

Slow decay exhibits the least current ripple of the decay modes for a given t_{OFF} . However on decreasing current steps, slow decay will take a long time to settle to the new I_{TRIP} level because the current decreases very slowly.



7.3.6.2 Mode 2: Slow Decay for Increasing Current, Mixed Decay for Decreasing Current

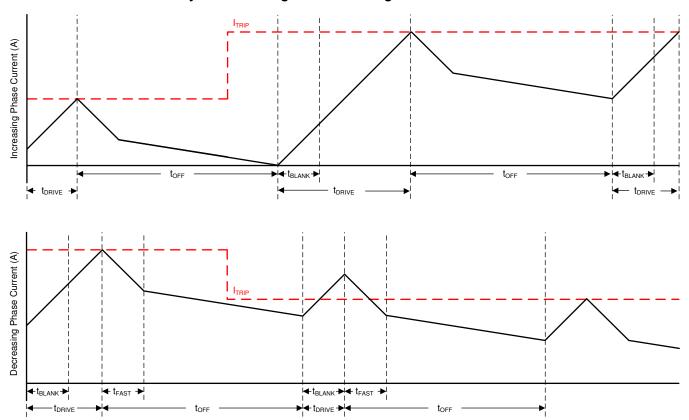
Figure 19. Slow/Mixed Decay Mode

Mixed decay begins as fast decay for a time, followed by slow decay for the remainder of t_{OFF}. In this mode, mixed decay only occurs during decreasing current. Slow decay is used for increasing current.

This mode exhibits the same current ripple as slow decay for increasing current, since for increasing current, only slow decay is used. For decreasing current, the ripple is larger than slow decay, but smaller than fast decay. On decreasing current steps, mixed decay will settle to the new I_{TRIP} level faster than slow decay.

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7.3.6.3 Mode 3: Mixed Decay for Increasing and Decreasing Current

Figure 20. Mixed/Mixed Decay Mode

Mixed decay begins as fast decay for a time, followed by slow decay for the remainder of t_{OFF}. In this mode, mixed decay occurs for both increasing and decreasing current steps.

This mode exhibits ripple larger than slow decay, but smaller than fast decay. On decreasing current steps, mixed decay will settle to the new I_{TRIP} level faster than slow decay.

In cases where current is held for a long time (no input in the STEP pin) or at very low stepping speeds, slow decay may not properly regulate current because no back-EMF is present across the motor windings. In this state, motor current can rise very quickly, and requires an excessively large off-time. Increasing/decreasing mixed decay mode allows the current level to stay in regulation when no back-EMF is present across the motor windings.



7.3.7 Blanking Time

After the current is enabled in an H-bridge, the current sense comparator is ignored for a period of time (t_{BLANK}) before enabling the current sense circuitry. Note that the blanking time also sets the minimum drive time of the PWM. Table 22 shows the blanking time based on the sine table index and the torque DAC setting. Please note that the torque DAC index is not the same as one step as given in Table 3.

Table 22. Adaptive Blanking Time over Torque DAC and Microsteps

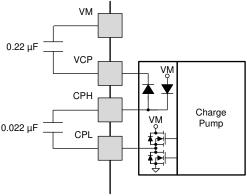
t_{blank} = 1.0 μs

t_{blank} = 1.5 μs

| L | | | |
|------------|------|----------------|-------|
| | T | ORQUE DAC (TRO | ג) |
| SINE INDEX | 100% | 75% | 50% |
| 16 | 100% | 75% | 50% |
| 15 | 98% | 73.5 | 49% |
| 14 | 96% | 72% | 48% |
| 13 | 92% | 69% | 46% |
| 12 | 88% | 66% | 44% |
| 11 | 83% | 62.3% | 41.5% |
| 10 | 77% | 57.8% | 38.5% |
| 9 | 71% | 53.3% | 35.5% |
| 8 | 63% | 47.3% | 31.5% |
| 7 | 56% | 42% | 28% |
| 6 | 47% | 35.3 | 23.5% |
| 5 | 38% | 28.5 | 19% |
| 4 | 29% | 21.8% | 14.5% |
| 3 | 20% | 15% | 10% |
| 2 | 10% | 7.5% | 5% |
| 1 | 0% | 0% | 0% |

7.3.8 Charge Pump

A charge pump is integrated in order to supply a high-side NMOS gate drive voltage. The charge pump requires a capacitor between the VM and VCP pins. Additionally a low ESR ceramic capacitor is required between pins CPH and CPL.



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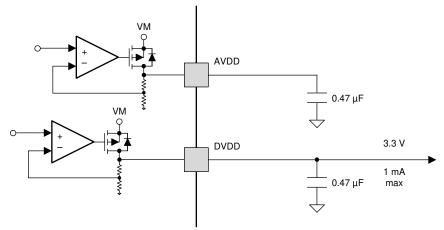


7.3.9 LDO Voltage Regulator

An LDO regulator is integrated into the DRV8885. DVDD can be used to provide a reference voltage. For proper operation, bypass DVDD to GND using a ceramic capacitor.

The DVDD output is nominally 3.3 V. When the DVDD LDO current load exceeds 1 mA, the output voltage will drop significantly.

The AVDD pin also requires a bypass capacitor to GND. This LDO is for DRV8885 internal use only.



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Figure 22. LDO Diagram

If a digital input needs to be tied permanently high (that is, Mx, DECAY or TRQ), it is preferable to tie the input to DVDD instead of an external regulator. This will save power when VM is not applied or in sleep mode: DVDD is disabled and current will not be flowing through the input pulldown resistors. For reference, logic level inputs have a typical pulldown of 100 k Ω , and tri-level inputs have a typical pulldown of 60 k Ω .

7.3.10 Logic and Multi-Level Pin Diagrams

Figure 23 gives the input structure for logic-level pins STEP, DIR, ENABLE, nSLEEP, M1:

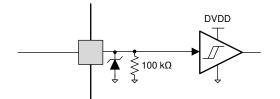


Figure 23. Logic-level Input Pin Diagram

Tri-level logic pins M0 and TRQ have the following structure:

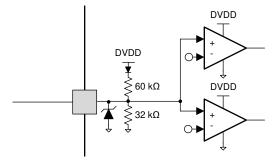


Figure 24. Tri-level Input Pin Diagram



Quad-level logic pin DECAY has the following structure:

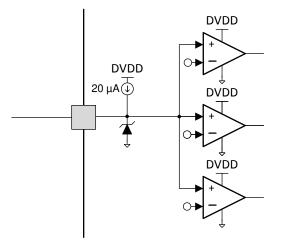


Figure 25. Quad-level Input Pin Diagram

7.3.11 Protection Circuits

The DRV8885 is fully protected against undervoltage, charge pump undervoltage, overcurrent, and overtemperature events.

7.3.11.1 VM Undervoltage Lockout (UVLO)

If at any time the voltage on the VM pin falls below the VM undervoltage lockout threshold voltage (V_{UVLO}), all FETs in the H-bridge will be disabled, the charge pump will be disabled, the logic will be reset, the DVDD regulator is disabled, and the nFAULT pin will be driven low. Operation will resume when VM rises above the UVLO threshold. The nFAULT pin will be released after operation has resumed. Decreasing VM below this undervoltage threshold will reset the indexer position.

7.3.11.2 VCP Undervoltage Lockout (CPUV)

If at any time the voltage on the VCP pin falls below the charge pump undervoltage lockout threshold voltage, all FETs in the H-bridge will be disabled and the nFAULT pin will be driven low. Operation will resume when VCP rises above the CPUV threshold. The nFAULT pin will be released after operation has resumed.

7.3.11.3 Overcurrent Protection (OCP)

An analog current limit circuit on each FET limits the current through the FET by removing the gate drive. If this analog current limit persists for longer than t_{OCP}, all FETs in the H-bridge will be disabled and nFAULT will be driven low.

The driver will be re-enabled after the OCP retry period (t_{RETRY}) has passed. nFAULT becomes high again at after the retry time. If the fault condition is still present, the cycle repeats. If the fault is no longer present, normal operation resumes and nFAULT remains deasserted.

7.3.11.4 Thermal Shutdown (TSD)

If the die temperature exceeds safe limits, all FETs in the H-bridge will be disabled and the nFAULT pin will be driven low. Once the die temperature has fallen to a safe level operation will automatically resume. The nFAULT pin will be released after operation has resumed.

| FAULT | CONDITION | ERROR REPORT | H-BRIDGE | CHARGE PUMP | INDEXER | DVDD | RECOVERY |
|----------------------------|--|-----------------|----------|----------------|-----------|-----------|---|
| VM undervoltage (UVLO) | VM < V _{UVLO} (max 7.8 V) | nFAULT | Disabled | Disabled | Disabled | Disabled | VM > V _{UVLO} (max 8.0 V) |
| VCP undervoltage (CPUV) | VCP < V _{CPUV} (typ VM + 2.0 V) | nFAULT | Disabled | Operating | Operating | Operating | VCP > V _{CPUV} (typ VM + 2.7 V) |
| Overcurrent (OCP) | I _{OUT} > I _{OCP} (min 2.1 A) | nFAULT | Disabled | Operating | Operating | Operating | t _{RETRY} |
| Thermal Shutdown (TSD) | T _J > T _{TSD} (min 150°C) | nFAULT | Disabled | Operating | Operating | Operating | T _J < T _{TSD} - T _{HYS} (T _{HYS} typ 20°C) |

Table 23. Fault Condition Summary

7.4 Device Functional Modes

The DRV8885 is active unless the nSLEEP pin is brought logic low. In sleep mode the charge pump is disabled, the H-bridge FETs are disabled Hi-Z, and the V3P3 regulator is disabled. Note that t_{SLEEP} must elapse after a falling edge on the nSLEEP pin before the device is in sleep mode. The DRV8885 is brought out of sleep mode automatically if nSLEEP is brought logic high. Note that t_{WAKE} must elapse before the outputs change state after wake-up.

TI recommends to keep the STEP pin logic low when coming out of nSLEEP or when applying power.

If the ENABLE pin is brought logic low, the H-bridge outputs are disabled, but the internal logic will still be active. A rising edge on STEP will advance the indexer, but the outputs will not change state until ENABLE is asserted.

| | CONDITION | H-BRIDGE | CHARGE PUMP | INDEXER | V3P3 |
|-------------------|---|-----------|-------------|-----------|-----------|
| Operating | 8 V < VM < 40 V nSLEEP pin = 1 ENABLE pin = 1 | Operating | Operating | Operating | Operating |
| Disabled | 8 V < VM < 40 V nSLEEP pin = 1 ENABLE pin = 0 | Disabled | Operating | Operating | Operating |
| Sleep mode | 8 V < VM < 40 nSLEEP pin = 0 | Disabled | Disabled | Disabled | Disabled |
| | VM undervoltage (UVLO) | Disabled | Disabled | Disabled | Disabled |
| | VCP undervoltage (CPUV) | Disabled | Operating | Operating | Operating |
| Fault encountered | Overcurrent (OCP) | Disabled | Operating | Operating | Operating |
| | Thermal Shutdown (TSD) | Disabled | Operating | Operating | Operating |

Table 24. Functional Modes Summary



8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The DRV8885 is used in bipolar stepper control.

8.2 Typical Application

The following design procedure can be used to configure the DRV8885.

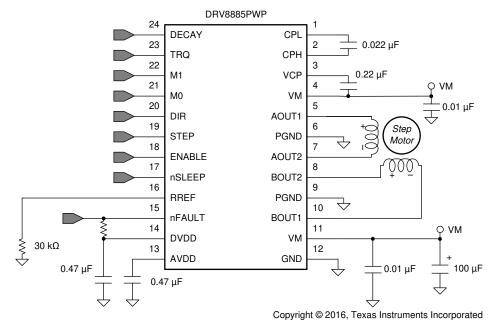


Figure 26. Typical Application Schematic

8.2.1 Design Requirements

Table 25 gives design input parameters for system design.

| DESIGN PARAMETER | REFERENCE | EXAMPLE VALUE |
|----------------------------|-----------------|---------------|
| Supply voltage | VM | 24 V |
| Motor winding resistance | RL | 2.6 Ω/phase |
| Motor winding inductance | L | 1.4 mH/phase |
| Motor full step angle | θ_{step} | 1.8°/step |
| Target microstepping level | n _m | 1/8 step |
| Target motor speed | V | 120 rpm |
| Target full-scale current | I _{FS} | 1.0 A |



8.2.2 Detailed Design Procedure

8.2.2.1 Stepper Motor Speed

The first step in configuring the DRV8885 requires the desired motor speed and microstepping level. If the target application requires a constant speed, then a square wave with frequency f_{step} must be applied to the STEP pin.

If the target motor speed is too high, the motor will not spin. Make sure that the motor can support the target speed.

For a desired motor speed (v), microstepping level (n_m), and motor full step angle (θ_{step}),

$$f_{\text{step}} (\text{steps / s}) = \frac{v (\text{rpm}) \times 360 (^{\circ}/\text{rot})}{\theta_{\text{step}} (^{\circ}/\text{step}) \times n_{\text{m}} (\text{steps / microstep}) \times 60 (\text{s / min})}$$
(5)

 θ_{step} can be found in the stepper motor data sheet, or written on the motor itself.

For the DRV8885, the microstepping level is set by the Mx pins and can be any of the settings in the table below. Higher microstepping will mean a smother motor motion and less audible noise, but will increase switching losses and require a higher fstep to achieve the same motor speed.

| | | J |
|----|----|---|
| M1 | MO | STEP MODE |
| 0 | 0 | Full step (2-phase excitation) with 71% current |
| 0 | 1 | 1/16 step |
| 1 | 0 | 1/2 step |
| 1 | 1 | 1/4 step |
| 0 | Z | 1/8 step |
| 1 | Z | Non-circular 1/2 step |

Table 26. Microstepping Indexer Settings

Example: Target 120 rpm at 1/8 microstep mode. The motor is 1.8°/step

$$f_{\text{step}} (\text{steps / s}) = \frac{120 \text{ rpm} \times 360^{\circ} / \text{ rot}}{1.8^{\circ} / \text{ steps } \times 1/8 \text{ steps } / \text{ microstep } \times 60 \text{ s} / \text{min}} = 3.2 \text{ kHz}$$
(6)

8.2.2.2 Current Regulation

In a stepper motor, the full-scale current (I_{FS}) is the maximum current driven through either winding. This quantity will depend on the RREF resistor and the TRQ setting. During stepping, I_{FS} defines the current chopping threshold (I_{TRIP}) for the maximum current step.

$$I_{FS}(A) = \frac{A_{RREF}(kA\Omega)}{RREF(k\Omega)} = \frac{30 (kA\Omega) \times TRQ\%}{RREF(k\Omega)}$$
(7)

Note that I_{FS} must also follow Equation 8 in order to avoid saturating the motor. VM is the motor supply voltage, and R_L is the motor winding resistance.

$$I_{FS}(A) < \frac{VM(V)}{R_{L}(\Omega) + 2 \times R_{DS(ON)}(\Omega)}$$
(8)

8.2.2.3 Decay Modes

The DRV8885 supports three different decay modes: slow decay, slow/mixed and all mixed decay. The current through the motor windings is regulated using an adjustable fixed-time-off scheme. This means that after any drive phase, when a motor winding current has hit the current chopping threshold (I_{TRIP}), the DRV8885 will place the winding in one of the three decay modes for t_{OFF} . After t_{OFF} , a new drive phase starts.

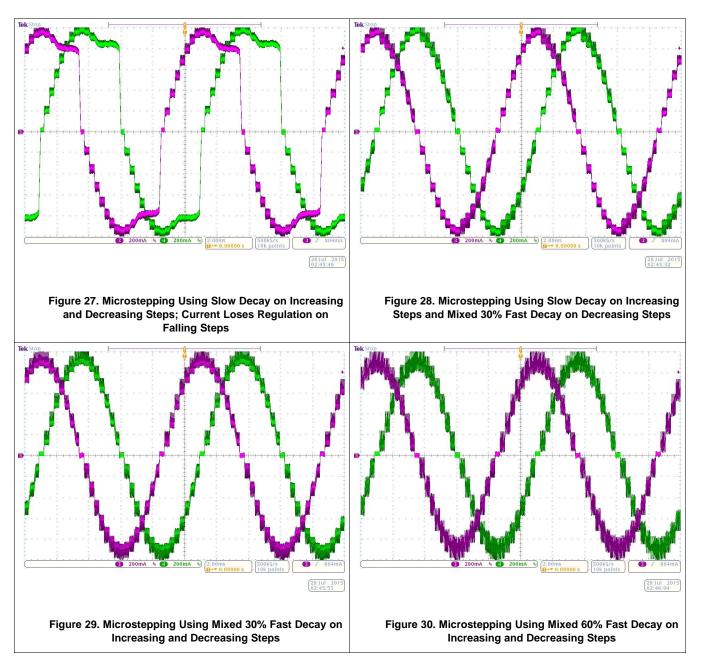
The blanking time t_{BLANK} defines the minimum drive time for the PWM current chopping. I_{TRIP} is ignored during t_{BLANK} , so the winding current may overshoot the trip level.

DRV8885 SLVSD39D-OCTOBER 2015-REVISED MARCH 2020



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8.2.3 Application Curves





9 Power Supply Recommendations

The DRV8885 is designed to operate from an input voltage supply (VM) range between 8 V and 35 V. A 0.01 μ F ceramic capacitor rated for VM must be placed at each VM pin as close to the DRV8885 as possible. In addition, a bulk capacitor must be included on VM.

9.1 Bulk Capacitance

Having appropriate local bulk capacitance is an important factor in motor drive system design. It is generally beneficial to have more bulk capacitance, while the disadvantages are increased cost and physical size.

The amount of local capacitance needed depends on a variety of factors, including:

- The highest current required by the motor system
- The power supply's capacitance and ability to source current
- The amount of parasitic inductance between the power supply and motor system
- The acceptable voltage ripple
- The type of motor used (brushed DC, brushless DC, stepper)
- The motor braking method

The inductance between the power supply and motor drive system will limit the rate current can change from the power supply. If the local bulk capacitance is too small, the system will respond to excessive current demands or dumps from the motor with a change in voltage. When adequate bulk capacitance is used, the motor voltage remains stable and high current can be quickly supplied.

The data sheet generally provides a recommended value, but system-level testing is required to determine the appropriate sized bulk capacitor.

The voltage rating for bulk capacitors should be higher than the operating voltage, to provide margin for cases when the motor transfers energy to the supply.

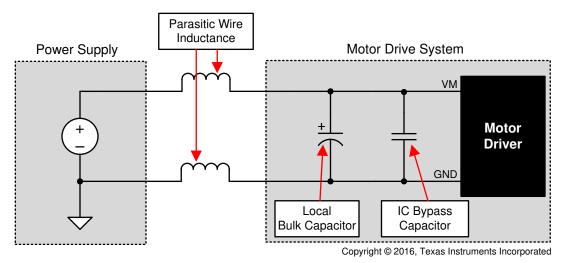


Figure 31. Example Setup of Motor Drive System With External Power Supply

TEXAS INSTRUMENTS

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10 Layout

10.1 Layout Guidelines

The VM terminal should be bypassed to GND using a low-ESR ceramic bypass capacitor with a recommended value of 0.01 μ F rated for VM. This capacitor should be placed as close to the VM pin as possible with a thick trace or ground plane connection to the device GND pin.

The VM pin must be bypassed to ground using a bulk capacitor rated for VM. This component may be an electrolytic.

A low-ESR ceramic capacitor must be placed in between the CPL and CPH pins. A value of 0.022 μ F rated for VM is recommended. Place this component as close to the pins as possible.

A low-ESR ceramic capacitor must be placed in between the VM and VCP pins. A value of 0.22 μ F rated for 16 V is recommended. Place this component as close to the pins as possible.

Bypass AVDD and DVDD to ground with a ceramic capacitor rated 6.3 V. Place this bypassing capacitor as close to the pin as possible.

10.2 Layout Example

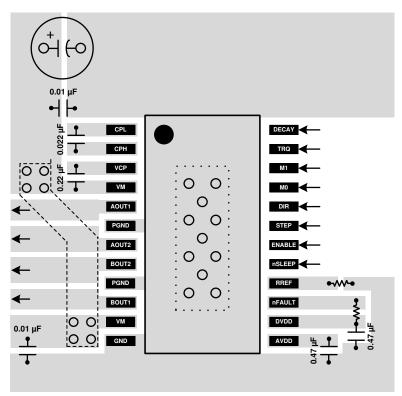


Figure 32. Layout Recommendation



11 Device and Documentation Support

11.1 Documentation Support

11.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, Calculating Motor Driver Power Dissipation application report
- Texas Instruments, Current Recirculation and Decay Modes application report
- Texas Instruments, Full-Scale Current Adjustment Using a Digital-to-Analog Converter (DAC) application report
- Texas Instruments, DRV8885 Evaluation Module (EVM) User's Guide
- Texas Instruments, PowerPAD™ Made Easy application report
- Texas Instruments, PowerPAD[™] Thermally Enhanced Package application report
- Texas Instruments, Understanding Motor Driver Current Ratings application report

11.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.3 Community Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

11.4 Trademarks

PowerPAD, E2E are trademarks of Texas Instruments. All other trademarks are the property of their respective owners.

11.5 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

11.6 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

| Orderable part number | Status | Material type | Package Pins | Package qty Carrier | RoHS | Lead finish/ | MSL rating/ | Op temp (°C) | Part marking |
|-----------------------|----------|---------------|-------------------|-----------------------|------|---------------|---------------------|--------------|--------------|
| | (1) | (2) | | | (3) | Ball material | Peak reflow | | (6) |
| | | | | | | (4) | (5) | | |
| DRV8885PWP | Obsolete | Production | HTSSOP (PWP) 24 | - | - | Call TI | Call TI | -40 to 125 | DRV8885 |
| DRV8885PWPR | Active | Production | HTSSOP (PWP) 24 | 2000 LARGE T&R | Yes | NIPDAU | Level-3-260C-168 HR | -40 to 125 | DRV8885 |
| DRV8885PWPR.A | Active | Production | HTSSOP (PWP) 24 | 2000 LARGE T&R | Yes | NIPDAU | Level-3-260C-168 HR | -40 to 125 | DRV8885 |
| DRV8885RHRR | Active | Production | WQFN (RHR) 28 | 3000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | DRV8885 |
| DRV8885RHRR.A | Active | Production | WQFN (RHR) 28 | 3000 LARGE T&R | Yes | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | DRV8885 |
| DRV8885RHRT | Obsolete | Production | WQFN (RHR) 28 | - | - | Call TI | Call TI | -40 to 125 | DRV8885 |

⁽¹⁾ **Status:** For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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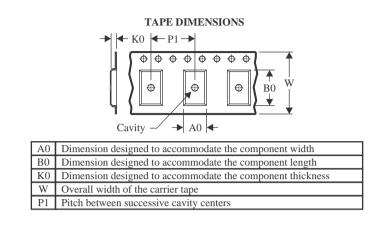
PACKAGE OPTION ADDENDUM

23-May-2025

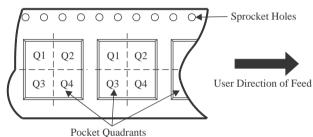


TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

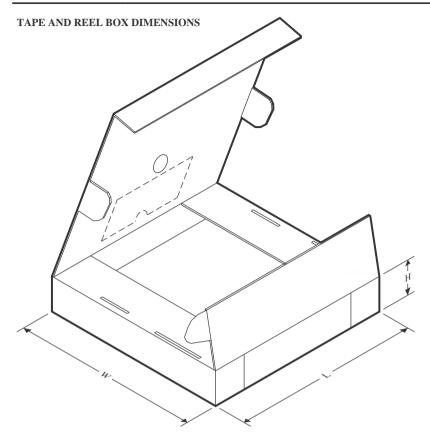


| *All dimensions are nominal | | | | | | | | | | | | |
|-----------------------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
| DRV8885PWPR | HTSSOP | PWP | 24 | 2000 | 330.0 | 16.4 | 6.95 | 8.3 | 1.6 | 8.0 | 16.0 | Q1 |
| DRV8885RHRR | WQFN | RHR | 28 | 3000 | 330.0 | 12.4 | 3.8 | 5.8 | 1.2 | 8.0 | 12.0 | Q1 |



PACKAGE MATERIALS INFORMATION

21-Mar-2025



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|-------------|--------------|-----------------|------|------|-------------|------------|-------------|
| DRV8885PWPR | HTSSOP | PWP | 24 | 2000 | 350.0 | 350.0 | 43.0 |
| DRV8885RHRR | WQFN | RHR | 28 | 3000 | 367.0 | 367.0 | 35.0 |

PWP 24

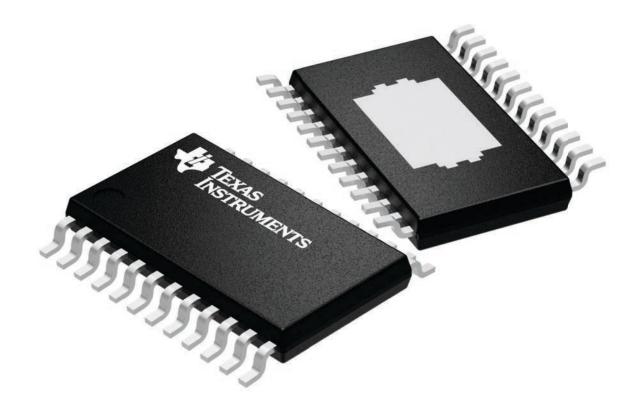
GENERIC PACKAGE VIEW

PLASTIC SMALL OUTLINE

PowerPAD[™] TSSOP - 1.2 mm max height

4.4 x 7.6, 0.65 mm pitch

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



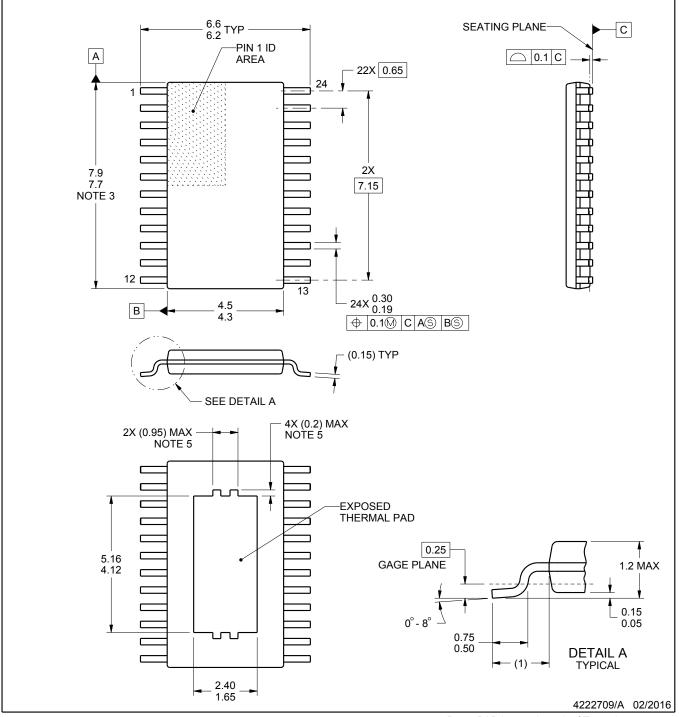


PACKAGE OUTLINE

PWP0024B

PowerPAD[™] TSSOP - 1.2 mm max height

PLASTIC SMALL OUTLINE



NOTES:

PowerPAD is a trademark of Texas Instruments.

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side. 4. Reference JEDEC registration MO-153.
- 5. Features may not be present and may vary.

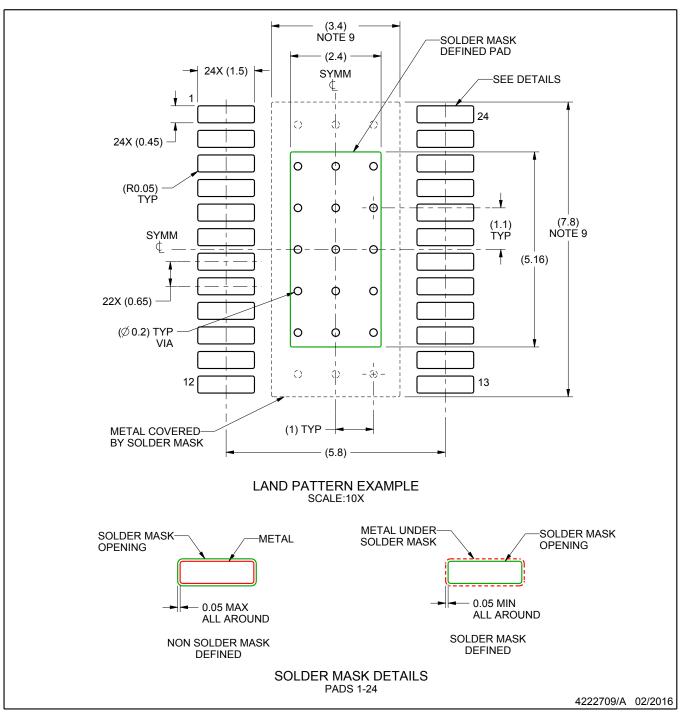


PWP0024B

EXAMPLE BOARD LAYOUT

PowerPAD[™] TSSOP - 1.2 mm max height

PLASTIC SMALL OUTLINE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

8. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002 (www.ti.com/lit/slma002) and SLMA004 (www.ti.com/lit/slma004).

9. Size of metal pad may vary due to creepage requirement.

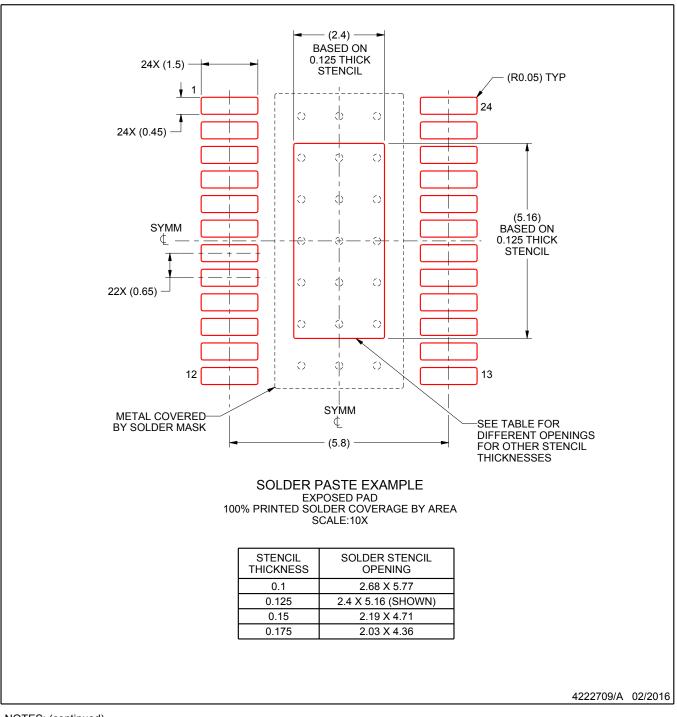


PWP0024B

EXAMPLE STENCIL DESIGN

PowerPAD[™] TSSOP - 1.2 mm max height

PLASTIC SMALL OUTLINE



NOTES: (continued)

11. Board assembly site may have different recommendations for stencil design.



^{10.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

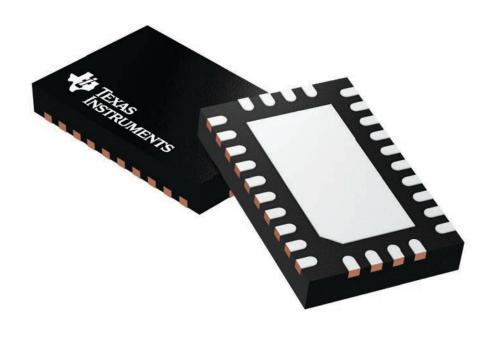
RHR 28

3.5 x 5.5, 0.5 mm pitch

GENERIC PACKAGE VIEW

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



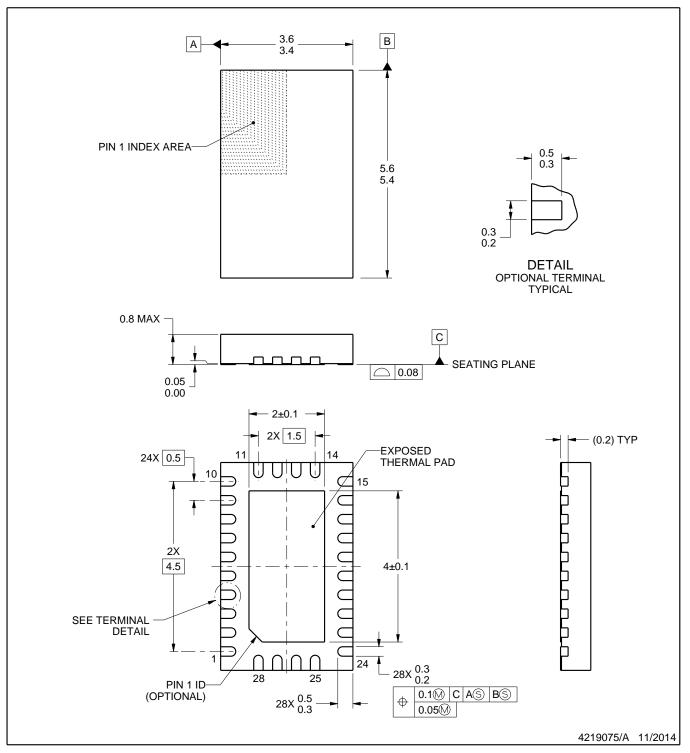
RHR0028A



PACKAGE OUTLINE

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

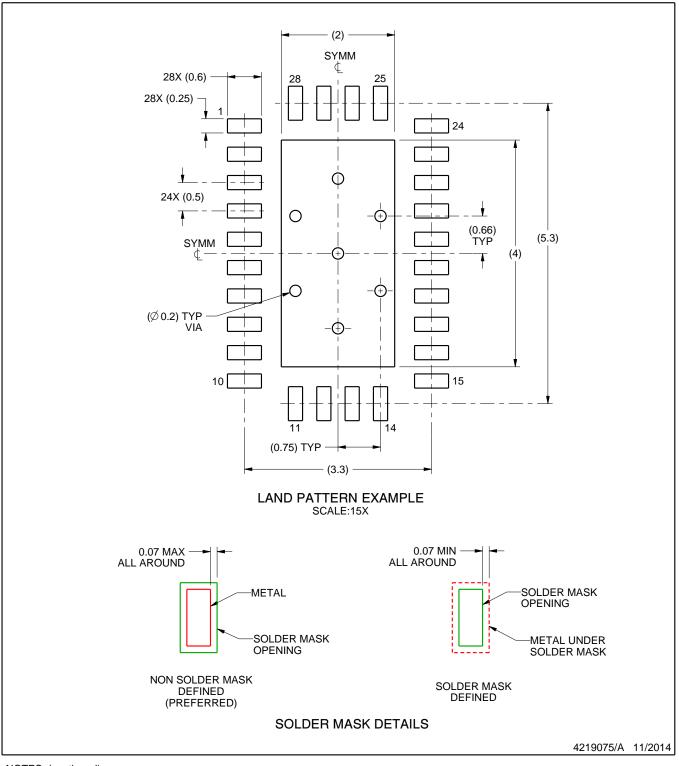


RHR0028A

EXAMPLE BOARD LAYOUT

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

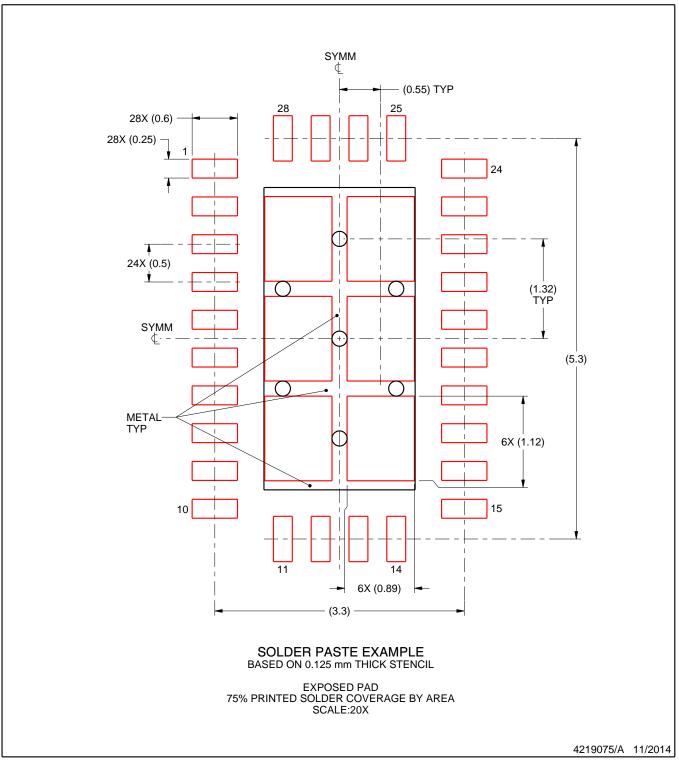


RHR0028A

EXAMPLE STENCIL DESIGN

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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